

## Low Voltage Dual SP3T Analog Switch 3:1 Mux/DeMux Bus Switch

### Features

- CMOS Technology for Bus and Analog Applications
- Low On-Resistance:  $0.5\Omega$  (typ) on channels 0 and 1  
 $1.65\Omega$  (typ) on channel 2
- Wide  $V_{CC}$  Range: 1.65V to 5.5V
- Rail-to-Rail Signal Range
- Control Input Overtoltage Tolerance: 5.5V min.
- High Off Isolation: -42dB
- Crosstalk Rejection Reduces Signal Distortion: -72dB
- Break-Before-Make Switching
- Low THD (0.02% typ @  $V_{CC} = 2.7V$  for channels 0 and 1)
- Extended Industrial Temperature Range: -40°C to 85°C
- Packaging: (Pb-free & Green)
  - 12-ball CSP

### Applications

- Cell Phones
- PDAs
- MP3 players
- Portable Instrumentation
- Computer Peripherals
- Speaker Headset Switching
- Power Routing
- Relay Replacement
- Audio and Video Signal Routing
- PCMCIA Cards
- Modems

### Pin Description

Pin #	Name	Description
A3, C3	$yA$	Common Output/Data Port
A1, A2, A4	$1Bx$	Data Port
C1, C2, C4	$2Bx$	Data Port
B2, B3	$S_0, S_1$	Logic Input Control
B1	GND	Ground
B4	$V_{CC}$	Positive Power Supply

**Note:**

1.  $x = 0, 1, \text{ or } 2$
2.  $y = 1 \text{ or } 2$

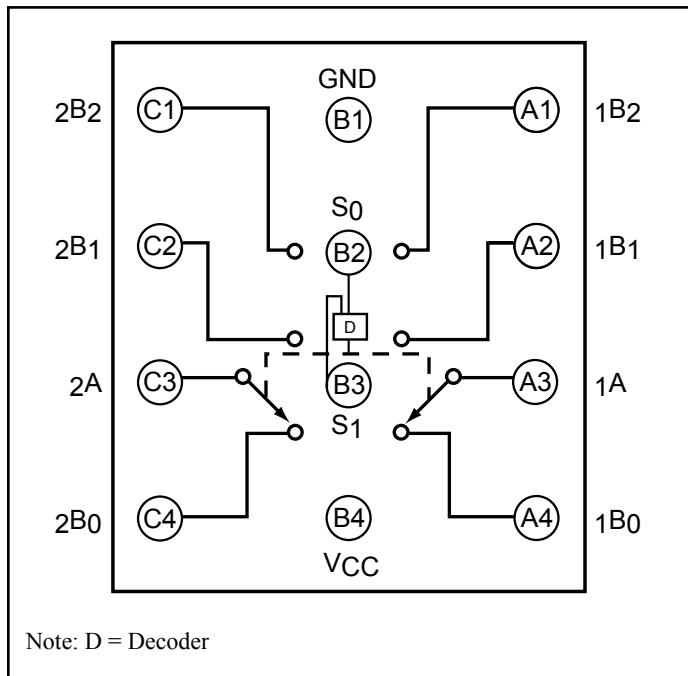
### Description

Pericom Semiconductor's PI5A4213 is a dual high-bandwidth, fast single-pole triple throw (SP3T) CMOS switch. It can be used as an analog switch or as a low-delay bus switch. The PI5A4213 is specified over a wide operating power supply voltage, 1.65V to 5.5V.

Break-before-make switching prevents both switches being enabled simultaneously. This eliminates signal disruption during switching.

The control input, S, tolerates input drive signals up to 6.0V, independent of supply voltage.

### Pin Configuration / Block Diagram (top view)



### Logic Function Table

Logic Input		Function
$S_1$	$S_0$	
0	0	$xB_0$ Connected to $xA$
0	1	$xB_1$ Connected to $xA$
1	0	$xB_2$ Connected to $xA$
1	1	No Connection

**Note:**

1.  $x = 1 \text{ or } 2$

### Absolute Maximum Ratings<sup>(1)</sup>

Supply Voltage V <sub>CC</sub> .....	-0.5V to +7V
DC Switch Voltage (V <sub>S</sub> ) <sup>(2)</sup> .....	-0.5V to V <sub>CC</sub> +0.5V
DC Input Voltage (V <sub>IN</sub> ) <sup>(2)</sup> .....	-0.5V to +7.0V
DC Output Current (V <sub>OUT</sub> ) .....	128mA
DC V <sub>CC</sub> or Ground Current (I <sub>CC</sub> /I <sub>GND</sub> ) .....	±100mA
Storage Temperature Range (T <sub>STG</sub> ) .....	-65°C to +150°C
Junction Temperature under Bias (T <sub>J</sub> ) .....	150°C
Junction Lead Temperature (T <sub>L</sub> ) (Soldering, 10 seconds) .....	260°C
Power Dissipation (P <sub>D</sub> ) @ +85°C .....	180mW

### Notes:

1. Absolute Maximum Ratings may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
2. The input and output negative voltage ratings may be exceeded if the inut and output diode current ratings are observed.
3. Control input must be held HIGH or LOW; it must not float.

### Recommended Operating Conditions<sup>(3)</sup>

Supply Voltage Operating (V <sub>CC</sub> ) .....	1.65V to 5.5V
Control Input Voltage (V <sub>IN</sub> ) .....	0V to V <sub>CC</sub>
Switch Input Voltage (V <sub>IN</sub> ) .....	0V to V <sub>CC</sub>
Output Voltage (V <sub>OUT</sub> ) .....	0V to V <sub>CC</sub>
Operating Temperature (T <sub>A</sub> ) .....	-40°C to +85°C
Input Rise and Fall Time (t <sub>r</sub> ,t <sub>f</sub> )	
Control Input V <sub>CC</sub> = 2.3V - 3.6V .....	0ns/V to 10ns/V
Control Input V <sub>CC</sub> = 4.5V - 5.5V .....	0ns/V to 5ns/V
Thermal Resistance ( $\theta_{JA}$ ) .....	350°C/W

**DC Electrical Characteristics +3V Supply**

( $V_{CC} = 2.7V$  to  $3.3V$ ,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $3V$  and  $+25^\circ C$ .)

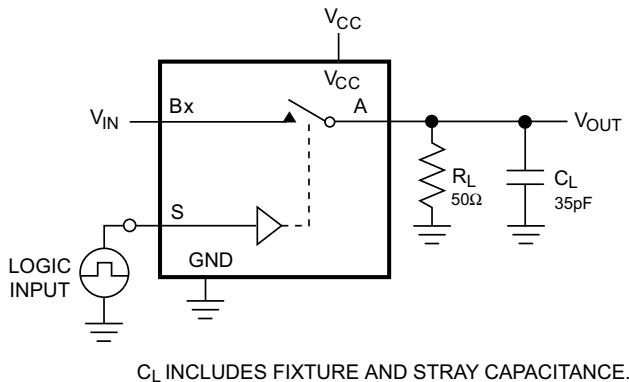
Parameter	Symbol	Test Conditions		Min.	Typ.	Max.	Units
<b>Analog Switch</b>							
Analog Signal Range	$V_A, V_B$			0		$V_{CC}$	V
On-Resistance	$R_{ON}$	$V_{CC} = 2.7V, I_A = 100mA,$ $V_B = 0$ to $V_{CC}$	ch. 2		1.6	2.0	$\Omega$
			ch.0 + 1		0.5		
On-Resistance Match Between Channels	$\Delta R_{ON}$	$V_{CC} = 2.7V, I_A = 100mA,$ $V_B = 1.5V$				0.1	
On-Resistance Flatness	$R_{ONF}$	$V_{CC} = 2.7V, I_A = 100mA,$ $V_B = 0$ to $V_{CC}$				0.5	
Off Leakage Current	$I_B$ (OFF)	$V_{CC} = 3.3V, V_B = 3V, 0.3V,$ $V_A = 0.3V, 3V$		-80		80	nA
On Leakage Current	$I_A$ (ON)	$V_{CC} = 3.3V, V_B = 3V, 0.3V,$ $V_A = 0.3V, 3V$ , or floating		-160		160	
<b>Digital I/O</b>							
Input Logic High	$V_{IH}$			1.8			V
Input Logic Low	$V_{IL}$					0.6	
S <sub>X</sub> Input Leakage Current	$I_{IN}$	$V_{IN} = 0$ or $V_{CC}$		-1		1	$\mu A$
<b>Power Supply</b>							
Power-Supply Range	$V_{CC}$			1.65		5.5	V
Supply Current	$I_{CC}$	$V_{CC} = 5.5V, V_{IN} = 0$ or $V_{CC}$			100	1000	nA

### Switch and AC Characteristics

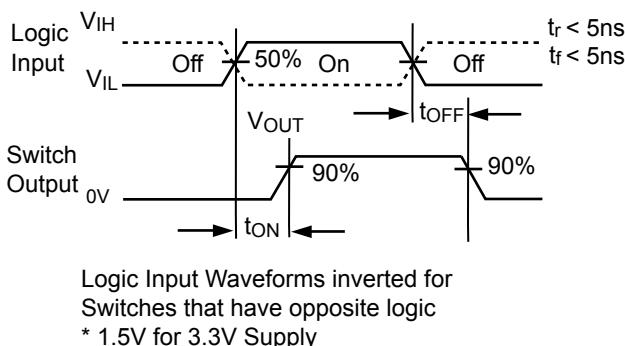
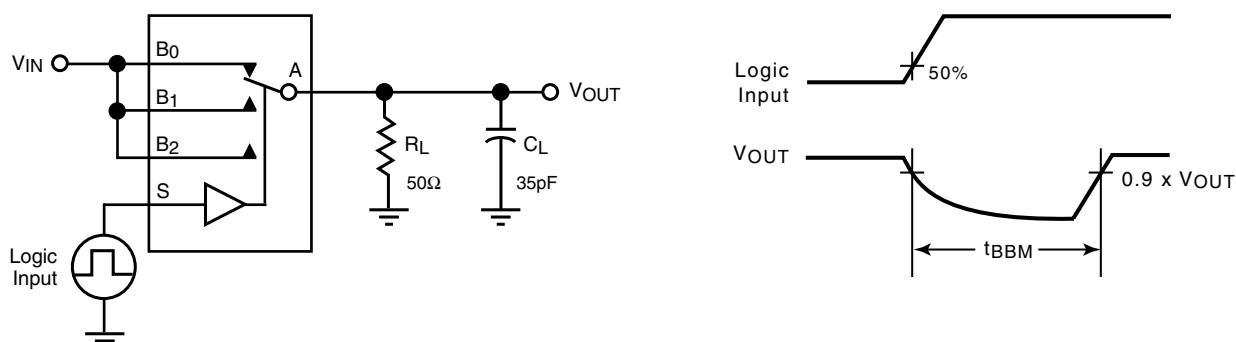
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Turn-On Time	t <sub>ON</sub>	V <sub>CC</sub> = 2.7V, V <sub>B</sub> = 1.5V, R <sub>L</sub> = 50Ω, C <sub>L</sub> = 35pF, See Test Circuit Fig. 1 & 2		13	15	ns
Turn-Off Time	t <sub>OFF</sub>	V <sub>CC</sub> = 2.7V, V <sub>B</sub> = 1.5V, R <sub>L</sub> = 50Ω, C <sub>L</sub> = 35pF, See Test Circuit Fig. 1 & 2		10.0	12	
Break-Before-Make Delay	t <sub>BBM</sub>	V <sub>CC</sub> = 2.7V, V <sub>B</sub> = 1.5V, R <sub>L</sub> = 50Ω, C <sub>L</sub> = 35pF, See Test Circuit Fig. 3	2	15.0		
Charge Injection	Q	V <sub>GEN</sub> = 0V, C <sub>L</sub> = 1nF, R <sub>GEN</sub> = 0Ω, See Test Circuit Fig. 4		35		pC
Off-Isolation	O <sub>IRR</sub>	C <sub>L</sub> = 5pF, R <sub>L</sub> = 50Ω, f = 100kHz, V <sub>A</sub> = 1 VRMS, See Test Circuit Fig. 5		-42		dB
Crosstalk	X <sub>TALK</sub>	C <sub>L</sub> = 5pF, R <sub>L</sub> = 50Ω, f = 100kHz, V <sub>A</sub> = 1 VRMS, See Test Circuit Fig. 6		-72		
3dB Bandwidth	f <sub>3dB</sub>	See Test Circuit Figure 9.		30		MHz
Total Harmonic Distortion	THD for ch. 0 and ch. 1	R <sub>L</sub> = 32Ω, V <sub>IN</sub> = 3.5V, V <sub>CC</sub> = 4.5V f = 20Hz to 20kHz		0.03		%
		R <sub>L</sub> = 32Ω, V <sub>IN</sub> = 2.0V, V <sub>CC</sub> = 3.4V f = 20Hz to 20kHz		0.025		
		R <sub>L</sub> = 32Ω, V <sub>IN</sub> = 1.5V, V <sub>CC</sub> = 2.7V f = 20Hz to 20kHz		0.02		
	THD for ch. 2	R <sub>L</sub> = 32Ω, V <sub>IN</sub> = 3.5V, V <sub>CC</sub> = 4.5V f = 20Hz to 20kHz		0.30		
		R <sub>L</sub> = 32Ω, V <sub>IN</sub> = 2.0V, V <sub>CC</sub> = 3.4V f = 20Hz to 20kHz		0.26		
		R <sub>L</sub> = 32Ω, V <sub>IN</sub> = 1.5V, V <sub>CC</sub> = 2.7V f = 20Hz to 20kHz		0.26		

### Capacitance

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Off Capacitance	C <sub>A</sub> (OFF)	f = 1 MHz, See Test Circuit Figure 7		50		pF
Off Capacitance	C <sub>B</sub> (OFF)	f = 1 MHz, See Test Circuit Figure 7		50		
On Capacitance	C <sub>ON</sub>	f = 1 MHz, See Test Circuit Figure 8		200		

**Test Circuits and Timing Diagrams**

**Notes:**

- Unused  $B_x$  inputs must be grounded.

**Figure 1. AC Test Circuit**

**Figure 2. AC Waveforms**

**Figure 3. Break Before Make Interval Timing**

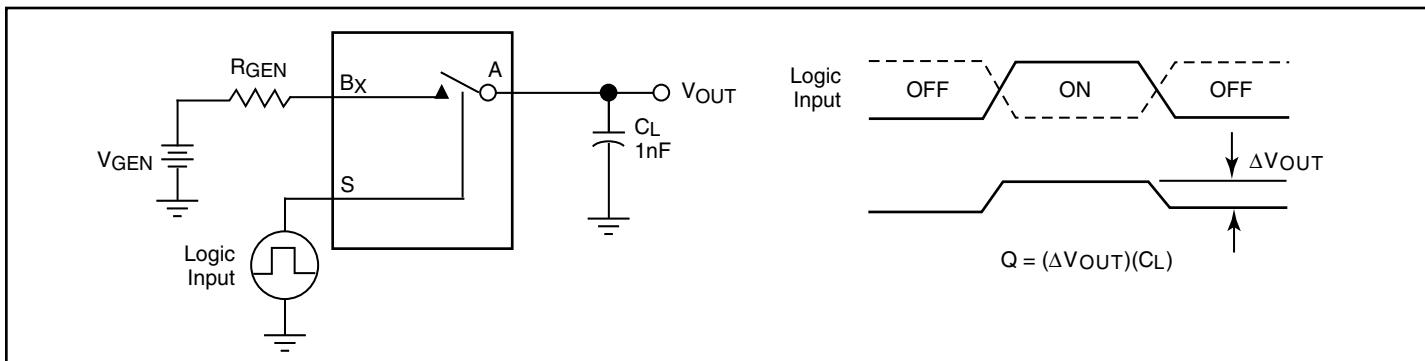


Figure 4. Charge Injection Test

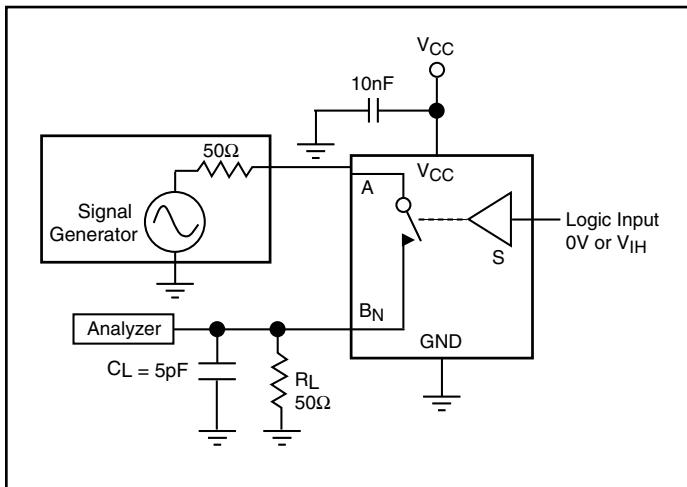


Figure 5. Off Isolation

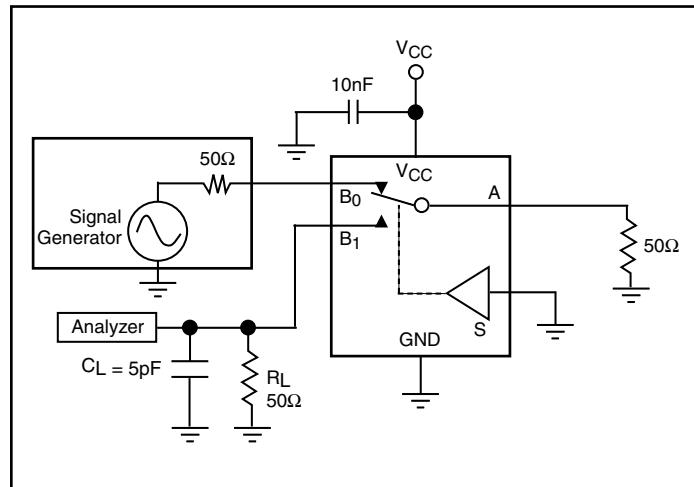


Figure 6. Crosstalk

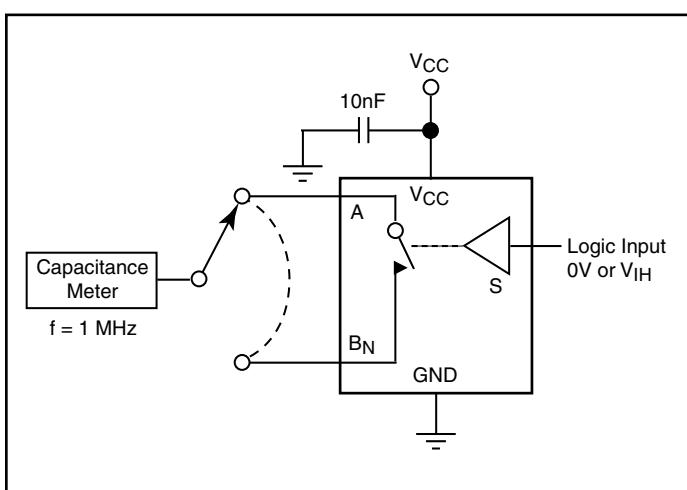


Figure 7. Channel Off Capacitance

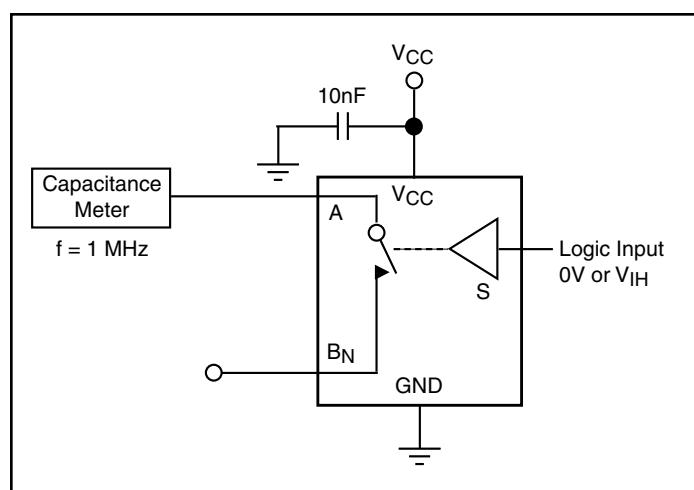
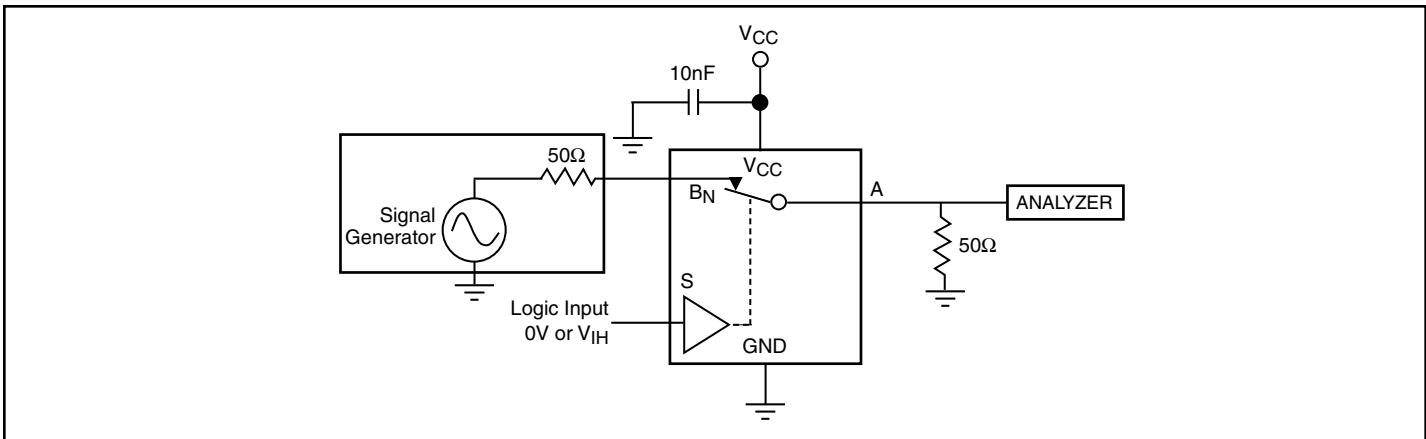
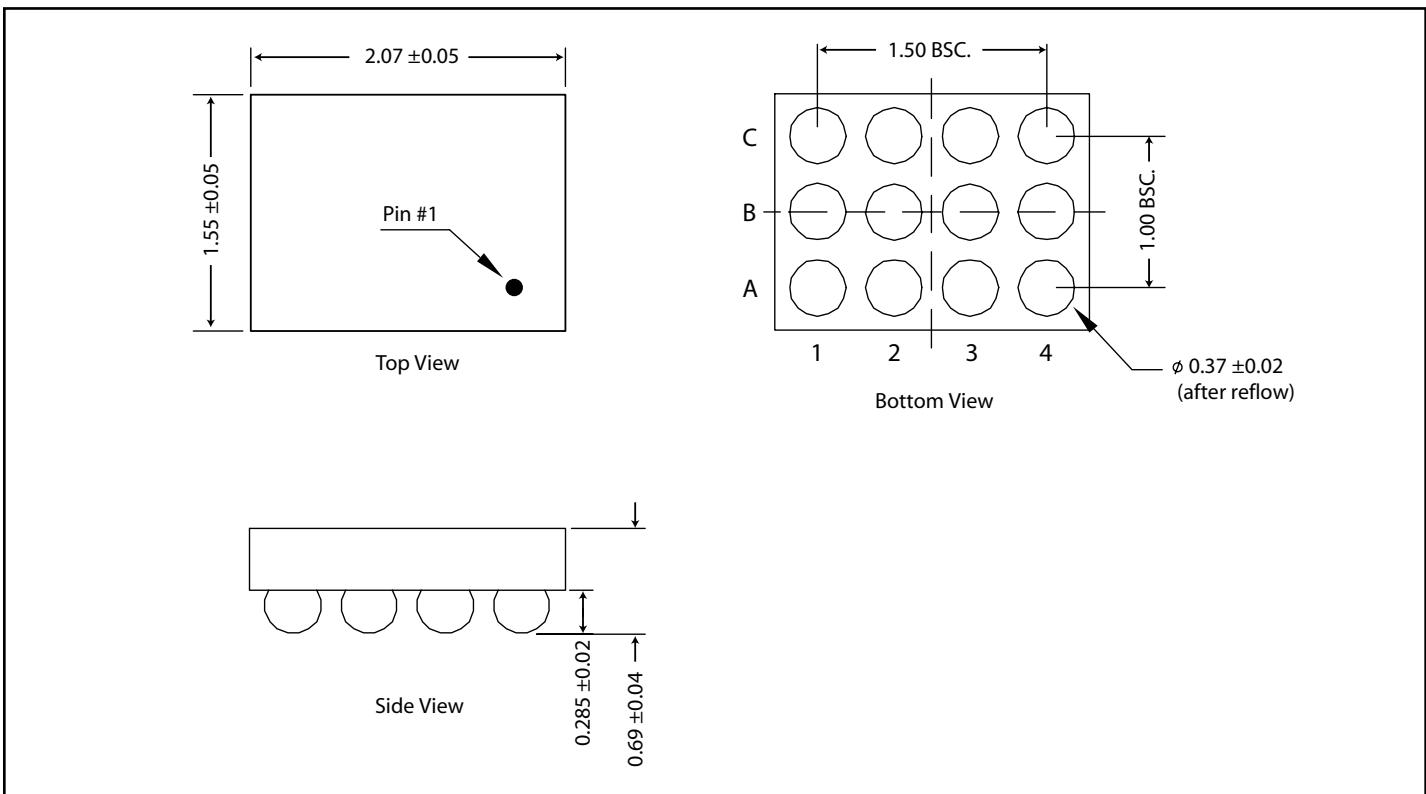


Figure 8. Channel On Capacitance


**Figure 9. Bandwidth**
**Packaging Mechanical : 2x1.5 mm CSP**

**Ordering Information**

Ordering Code	Packaging Code	Package Type
PI5A4213GAE	GA	Pb-free & Green, 12-ball CSP

**Note:**

- Thermal characteristics can be found on the company web site at [www.pericom.com/packaging/](http://www.pericom.com/packaging/)
- X suffix = Tape & Reel
- E = Pb-free & Green